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April 1st, 2010 Renesas Electronics Corporation

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EFFECT TRANSISTOR 2SK4148

SWITCHING N-CHANNEL MOSFET

DESCRIPTION

The 2SK4148 is a switching element that is most suitable for use in DC-DC converter whose DC input voltage is 24 to 48 V.

Having low on-resistance, and excelling in the switching characteristics, the 2SK4148 is ideal for use in high-speed switching.

FEATURES

- · Low input capacitance
 - Ciss = 120 pF TYP.
- · Low on-state resistance

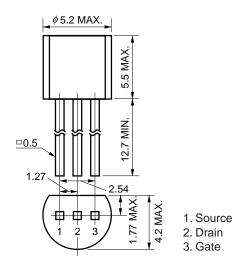
 $R_{DS(on)1} = 4.5 \Omega MAX. (V_{GS} = 10 V, I_{D} = 0.25 A)$

 $R_{DS(on)2} = 5.2 \Omega MAX. (V_{GS} = 4.5 V, I_{D} = 0.25 A)$

RDS(on)3 = 6.0Ω MAX. (VGS = 4 V, ID = 0.25 A)

- 4.5 V drive available
- Through hole mount package (TO-92)

PACKAGE DRAWING (Unit: mm)



ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE	
2SK4148-AZ Note	0- 4- 0-	500 p/package	TO-92 (SC-43A)	
2SK4148-T-AZ Note	Sn-Ag-Cu	Box type Tape 2500 p/box	0.26 g TYP.	

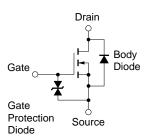
Note Pb-free (This product does not contain Pb in the external electrode.)

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (V _{GS} = 0 V)	VDSS	250	V
Gate to Source Voltage (VDS = 0 V)	Vgss	±20	V
Drain Current (DC) (T _A = 25°C)	ID(DC)	±0.5	Α
Drain Current (pulse) Note	ID(pulse)	±2.0	Α
Total Power Dissipation (T _A = 25°C)	PT	0.75	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C

Note PW \leq 10 μ s, Duty Cycle \leq 1%

EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD.

When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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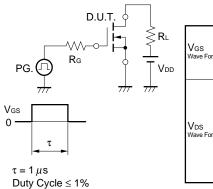
NEC

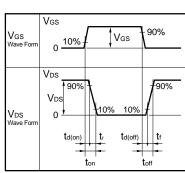
ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 250 V, V _{GS} = 0 V			10	μΑ
Gate Leakage Current	Igss	V _{GS} = ±20 V, V _{DS} = 0 V			±10	μΑ
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.0	1.9	2.5	V
Forward Transfer Admittance Note	y fs	V _{DS} = 10 V, I _D = 0.25 A	0.55			S
Drain to Source On-state Resistance Note	RDS(on)1	V _{GS} = 10 V, I _D = 0.25 A		3.6	4.5	Ω
	RDS(on)2	V _{GS} = 4.5 V, I _D = 0.25 A		3.6	5.2	Ω
	RDS(on)3	V _{GS} = 4 V, I _D = 0.25 A		3.6	6.0	Ω
Input Capacitance	Ciss	V _{DS} = 10 V,		120		pF
Output Capacitance	Coss	V _{GS} = 0 V,		18		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		7		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 125 V, I _D = 0.25 A,		5.5		ns
Rise Time	tr	V _{GS} = 10 V,		6		ns
Turn-off Delay Time	t _{d(off)}	R _G = 10 Ω		16.5		ns
Fall Time	tf			32		ns
Total Gate Charge	Q _G	V _{DD} = 200 V,		5.5		nC
Gate to Source Charge	Qgs	V _{GS} = 10 V,		1		nC
Gate to Drain Charge	Q _{GD}	ID = 0.5 A		2		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	I _F = 0.5 A, V _{GS} = 0 V		0.84	1.5	V
Reverse Recovery Time	trr	I _F = 0.5 A, V _{GS} = 0 V,		55		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs	-	54		nC

Note Pulsed

TEST CIRCUIT 1 SWITCHING TIME





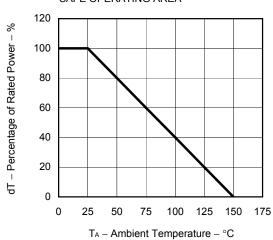
TEST CIRCUIT 2 GATE CHARGE





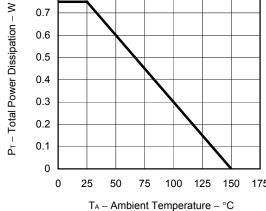
TYPICAL CHARACTERISTICS (TA = 25°C)

DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA

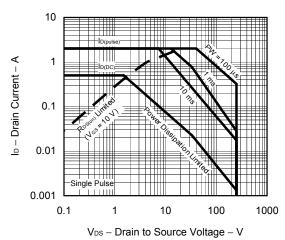


AMBIENT TEMPERATURE 8.0 0.7 0.6

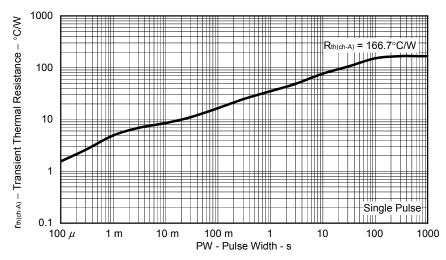
TOTAL POWER DISSIPATION vs.



FORWARD BIAS SAFE OPERATING AREA



TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



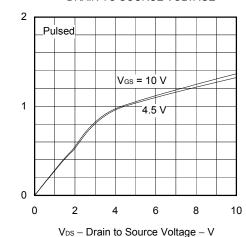




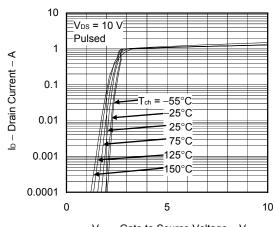
Ip - Drain Current - A

Phase-out/Discontinued

DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE

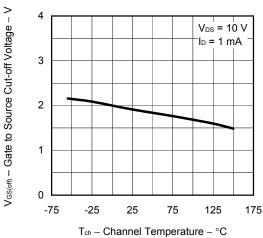


FORWARD TRANSFER CHARACTERISTICS

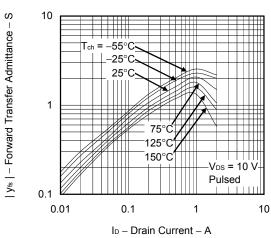


V_{GS} – Gate to Source Voltage – V

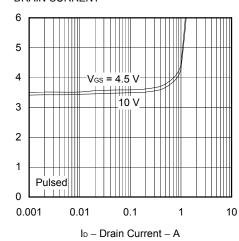
GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



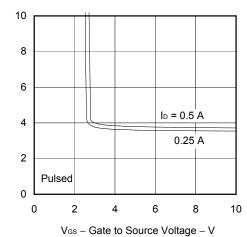
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



 $\mathsf{R}_{\mathsf{DS}(\varpi)}-\mathsf{Drain}$ to Source On-state Resistance – Ω

 $\mathsf{R}_{\mathsf{DS}(\mathsf{cn})}$ – Drain to Source On-state Resistance – Ω

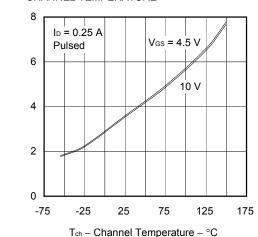




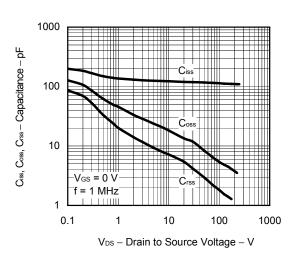
 $\mathsf{R}_{\mathsf{DS}(\varpi)}-\mathsf{Drain}$ to Source On-state Resistance $-\Omega$



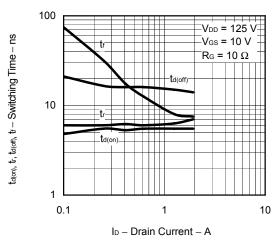
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



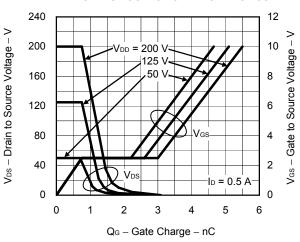
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



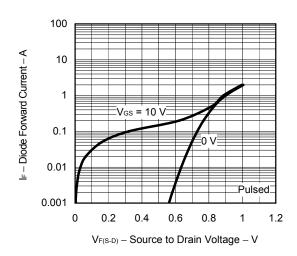
SWITCHING CHARACTERISTICS



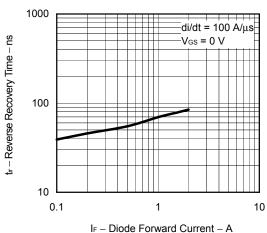
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT





NEC 2SK4148

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